NSN 5961-01-015-3815

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-015-3815 **Inclosure Material:** Metal **Overall Length:** Between 0.790 inches and 0.810 inches **Overall Height:** Between 0.149 inches and 0.187 inches Overall Width: 0.740 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 3.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 500.00 microamperes zero-gate-voltage source current preset and 4.00 amperes source cutoff current **Transfer Ratio:** 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 12909-403246 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ribbon and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**